

Supporting Information for:

**Highly Efficient Hybrid Light-Emitting Transistors incorporating
MoO_x/Ag/MoO_x Semi-Transparent Electrodes**

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1. Electrical and optical output characteristics of HLETs with OMO electrodes

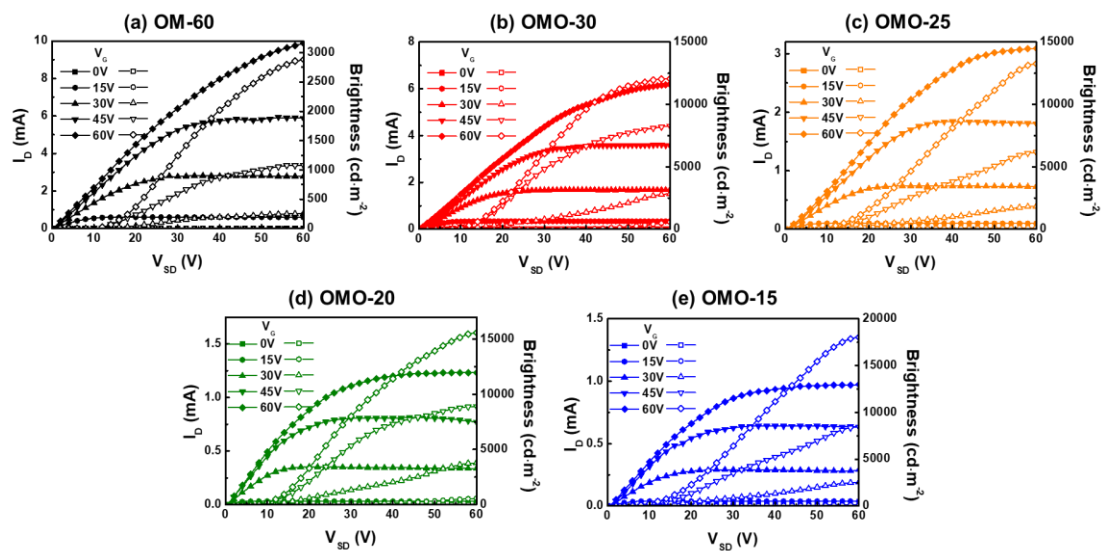


Figure S1. Electrical and optical output characteristics of HLETs with OMO electrodes as a function of Ag thicknesses (60, 30, 25, 20 and 15 nm, respectively.)